

9097250 TOSHIBA (DISCRETE/OPTO)

56C 07939 U T-33-09

2SD1405

SILICON NPN TRIPLE DIFFUSED TYPE

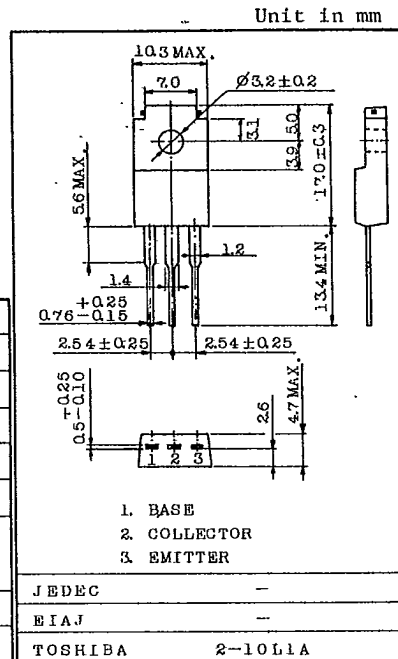
AUDIO FREQUENCY POWER AMPLIFIER APPLICATIONS.

FEATURES:

- High DC Current Gain of 200 to 1200 at $V_{CE}=5V$, $I_C=0.5A$
- Low $V_{CE(sat)}$ of 1.0V (Max.) at $I_C=1A$, $I_B=0.02A$
- Collector Power Dissipation of 25W at $T_c=25^\circ C$

MAXIMUM RATINGS ($T_a=25^\circ C$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	50	V
Emitter-Base Voltage	V_{EBO}	7	V
Collector Current	I_C	3	A
Base Current	I_B	0.5	A
Collector Power Dissipation	P_C	2.0	W
		25	
Junction Temperature	T_j	150	$^\circ C$
Storage Temperature Range	T_{stg}	-55 ~ 150	$^\circ C$



Weight : 2.1g

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ C$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=50V$, $I_E=0$	-	-	100	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=7V$, $I_C=0$	-	-	100	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=50mA$, $I_B=0$	50	-	-	V
DC Current Gain	h_{FE} (Note)	$V_{CE}=5V$, $I_C=0.5A$	200	-	1200	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=1A$, $I_B=0.02A$	-	0.25	1.0	V
Base-Emitter Voltage	V_{BE}	$V_{CE}=5V$, $I_C=0.5A$	-	0.7	1.0	V
Transition Frequency	f_T	$V_{CE}=5V$, $I_C=0.5A$	-	5.0	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V$, $I_E=0$, $f=1MHz$	-	70	-	pF
Switching Time	Turn-on Time	20ns INPUT I_{B1} I_{B2} OUTPUT I_{B1} I_{B2} $V_{CC}=10V$	-	2.0	-	μs
	Storage Time		-	5.0	-	
	Fall Time		-	3.0	-	

Note : h_{FE} Classification GR : 200 ~ 400, BL : 350 ~ 700, V : 600 ~ 1200

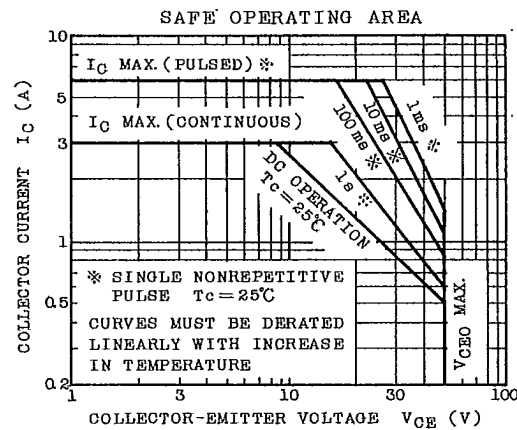
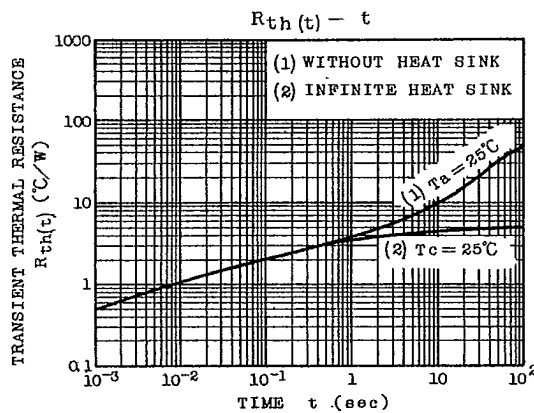
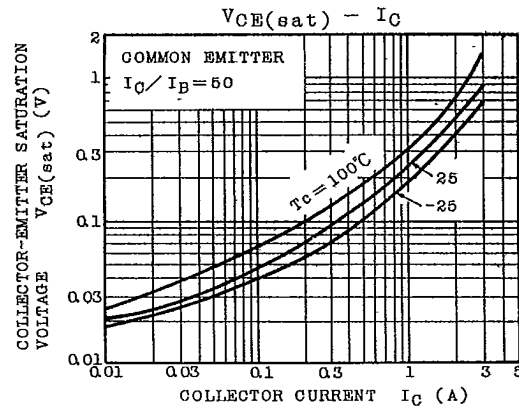
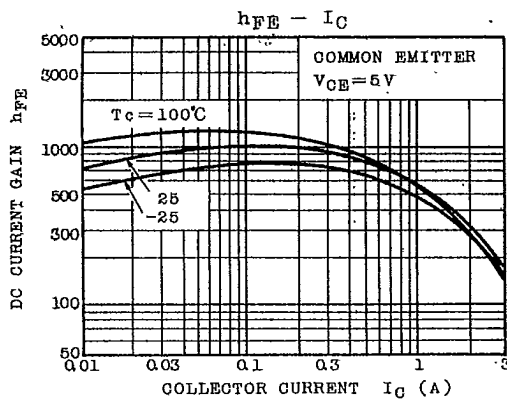
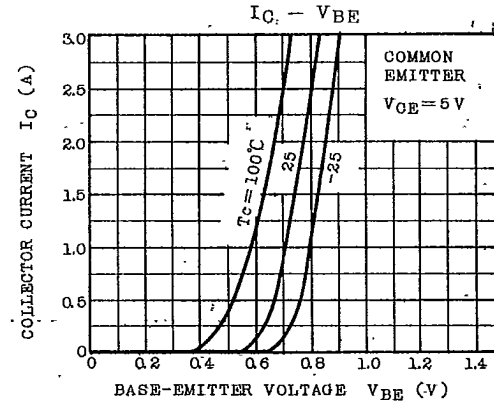
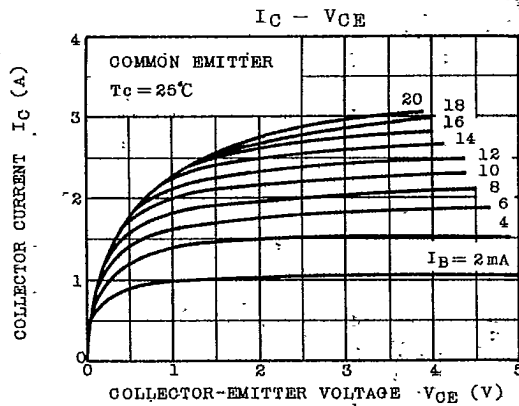
TOSHIBA CORPORATION

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